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# ͶͶΧΙΛΝ Low Noise, High-Precision Op Amps

### **General Description**

Applications

The MAX427/MAX437 ±15V operational amplifiers feature a superior combination of low wideband noise, and ultralow offset voltage and drift; 2.5nV/VHz (1kHz) noise, less than 15µV offset voltage (5µV typ), and less than 0.8µV/°C drift (0.1µV/°C typ). Voltage gain is 20 million when driving a  $2k\Omega$  load to  $\pm 12V$ , and 12 million with a  $600\Omega$  load to  $\pm 10V$ .

The MAX427 is unity-gain stable, with an 8MHz gain bandwidth and a 2.5V/µs slew rate. The decompensated MAX437 has a 60MHz gain bandwidth, a 15V/µs slew rate, and is stable for closed-loop gains of 5 or greater.

For applications requiring even lower noise and lowpower performance from ±5V supplies, see the MAX410/MAX412/MAX414 data sheet.

Low-Noise Signal Processing

**Threshold Detection** Strain-Gauge Amplifiers **Microphone Preamplifiers** 

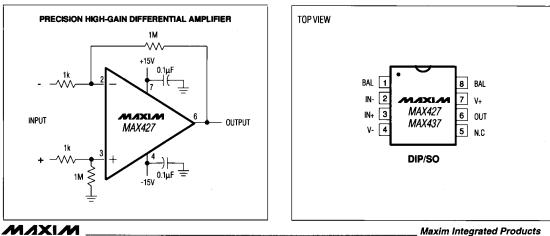
- ♦ 15µV Max Offset Voltage
- ♦ 0.8uV/°C Max Drift
- Low Noise Performance: 4.5nV/√<u>Hz</u> Max (10Hz) 3.8nV/√Hz Max (1kHz)
- High-Voltage Gain:
  7 Million Min (2kΩ Load)
  3 Million Min (600Ω Load)
- 117dB Min CMRR
- ♦ 60MHz Gain-Bandwidth Product (MAX437)

#### **Ordering Information**

PART	TEMP. RANGE	PIN-PACKAGE
MAX427CPA	0°C to +70°C	8 Plastic DIP
MAX427CSA	0°C to +70°C	8 SO
MAX427C/D	0°C to +70°C	Dice*
MAX427EPA	-40°C to +85°C	8 Plastic DIP
MAX427ESA	-40°C to +85°C	8 SO
MAX427MJA	-55°C to +125°C	8 CERDIP**
MAX437CPA	0°C to +70°C	8 Plastic DIP
MAX437CSA	0°C to +70°C	8 SO
MAX437C/D	0°C to +70°C	Dice*
MAX437EPA	-40°C to +85°C	8 Plastic DIP
MAX437ESA	-40°C to +85°C	8 SO
MAX437MJA	-55°C to +125°C	8 CERDIP**

\* Dice are specified at  $T_A = +25^{\circ}C$ , DC parameters only. \*\*Contact factory for availability and processing to MIL-STD-883.

#### Pin Configuration



### **Typical Application Circuit**

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**Features** 

### **ABSOLUTE MAXIMUM RATINGS**

Supply Voltage ±22V
Input Voltage (Note 1) ±22V
Output Short-Circuit Duration
Differential Input Voltage (Note 2)
Differential Input Current (Note 2) ±25mA
Continuous Power Dissipation ( $T_A = +70^{\circ}C$ )
Plastic DIP (derate 9.09mW/°C above +70°C) 727mW
SO (derate 5.88mW/°C above +70°C) 471mW
CERDIP (derate 8.00mW/°C above +70°C) 640mW

Operating Temperature Ranges:
MAX427/MAX437C_A 0°C to +70°C
MAX427/MAX437E_A40°C to +85°C
MAX427/MAX437MJA
Junction Temperature Range
Storage Temperature Range
Lead Temperature (soldering, 10 sec)+300°C

Note 1: For supply voltages less than ±22V, the absolute maximum input voltage is equal to the supply voltage.
 Note 2: MAX427/MAX437 inputs are protected by back-to-back diodes. Current-limiting resistors are not used in order to achieve low noise. If differential input voltage exceeds ±0.7V, the input current should be limited to 25mA.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

# **ELECTRICAL CHARACTERISTICS** ( $V_S = \pm 15V$ , $T_A = +25$ °C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	ΤΥΡ	MAX	UNITS	
Input Offset Voltage (Note 3)	Vos			5	15	μV	
Long-Term Vos Stability (Notes 4, 5)	Vos/TIME			0.2	1.0	μV/Mo	
Input Bias Current	lв			±10	±35	nA	
Input Offset Current	los			7	30	nA	
Input Voltage Range	IVR		±11.0	±12.5		V	
Input Resistance - Common Mode	RINCM			7		GΩ	
Input Noise Voltage (Notes 5, 6)	enp-p	0.1Hz to 10Hz		0.06	0.13	μVρ-ρ	
Input Noise-Voltage Density (Note 5)		f <sub>o</sub> = 10Hz		2.8	4.5	nV∕√Hz	
	en	f <sub>o</sub> = 1kHz		2.5	3.8		
Input Noise-Current Density		f <sub>o</sub> = 10Hz		1.5	4.0	pA∕√Hz	
(Notes 5, 7)	İn	f <sub>o</sub> = 1kHz		0.4	0.6		
Large-Signal Voltage Gain	Avo	$R_L \ge 2k\Omega$ , $V_O = \pm 12V$	7	20			
		$R_L \ge 1k\Omega$ , $V_O = \pm 10V$	5	16			
		$R_L \ge 600\Omega$ , $V_O = \pm 10V$	3	12			
Output Voltage Swing	Vo	R <sub>L</sub> ≥ 2kΩ	±13.0	±13.8		v	
		R <sub>L</sub> ≥ 600Ω	±11.0	±12.5			
Open-Loop Output Resistance	Ro	V <sub>O</sub> = 0, I <sub>O</sub> = 0		70		Ω	
Common-Mode Rejection Ratio	CMRR	V <sub>CM</sub> = ±11V	117	130		dB	
Power-Supply Rejection Ratio	PSRR	$V_S = \pm 4V$ to $\pm 18V$	110	130		dB	
Gain-Bandwidth Product (Note 5)	GBP	MAX427, f <sub>o</sub> = 100kHz	5.0	8.0		MHz	
		MAX437, f <sub>o</sub> = 10kHz, Av <sub>CL</sub> ≥ 5	45	60			
Slew Rate (Note 5)	SR	MAX427, RiL ≥ 2kΩ	1.7	2.8		- V/μs	
		MAX437, RL ≥ 2kΩ, AvcL ≥ 5	11	17			
Power Dissipation	PD	V <sub>O</sub> = 0		80	120	mW	
Offset Adjustment Range		$R_P = 10k\Omega$		±4.0		mV	

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### **ELECTRICAL CHARACTERISTICS**

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
Input Offset Voltage (Note 3)	Vos			20	50	μV	
Average Offset-Voltage Drift (Notes 5, 8)	TCVos			0.1	0.8	μV/°C	
Input Bias Current	Iв			±20	±60	nA	
Input Offset Current	los			15	50	nA	
Input Voltage Range	IVR	MAX4_7C/E	±10.5	±11.8			
		MAX4_7M	±10.3	±11.5		] *	
Large-Signal Voltage Gain	AVo	$R_L \ge 2k\Omega$ , $V_O = \pm 10V$	3.0	14.0		MAN	
		$R_L \ge 1k\Omega$ , $V_O = \pm 10V$	2.0	10.0		- V/μV	
Maximum Output-Voltage Swing	Vo	R <sub>L</sub> ≥ 2kΩ	±12.5	±13.5		V	
Common-Mode Rejection Ratio	CMRR	$V_{CM} = \pm 10V$	112	126		dB	
Power-Supply Rejection Ratio	PSRR	$V_{\rm S} = \pm 4.5 V$ to $\pm 18 V$	104	126		dB	
Power Dissipation	PD			100	150	mW	

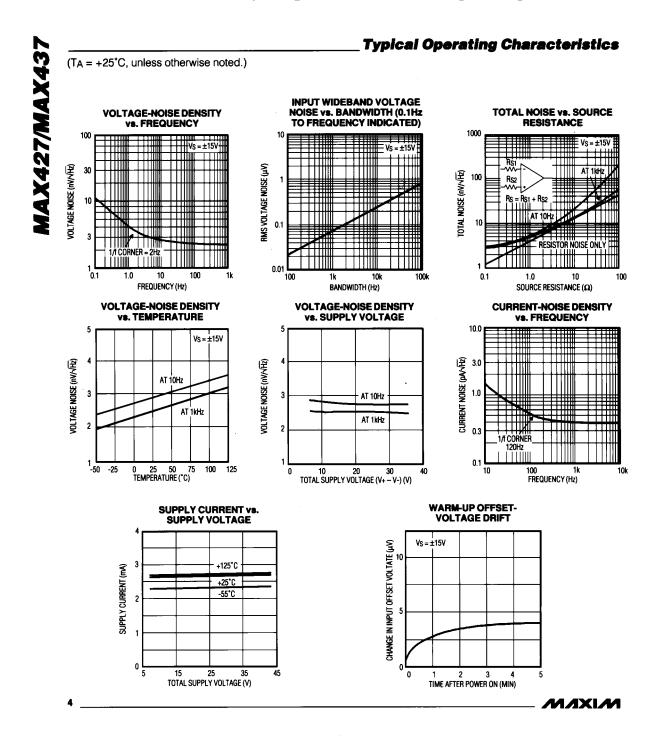
Note 3: Input Offset Voltage measurements are performed by automatic test equipment approximately 0.5 sec after application

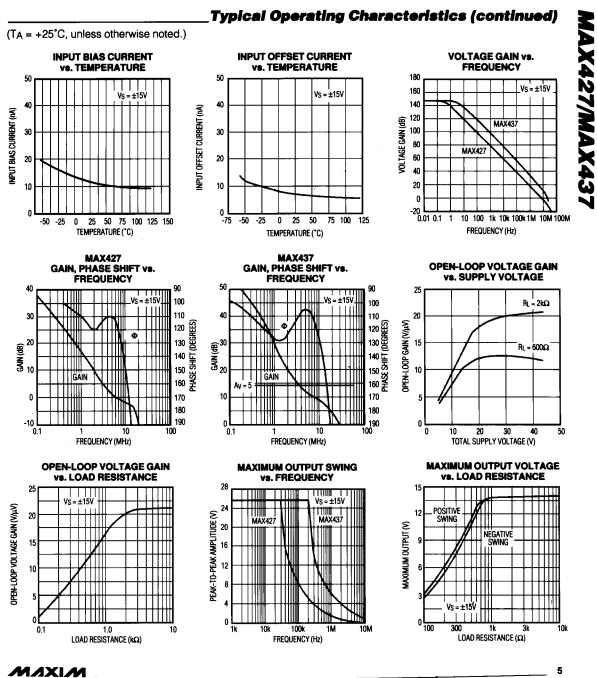
Note 4: Long-Term Input Offset Voltage Stability refers to the average trend line of Offset Voltage vs. Time over extended periods after the first 30 days of operation. Excluding the initial hour of operation, changes in Vos during the first 30 days are typically 2.5µV – refer to typical performance curve.
 Note 5: Guaranteed by design.

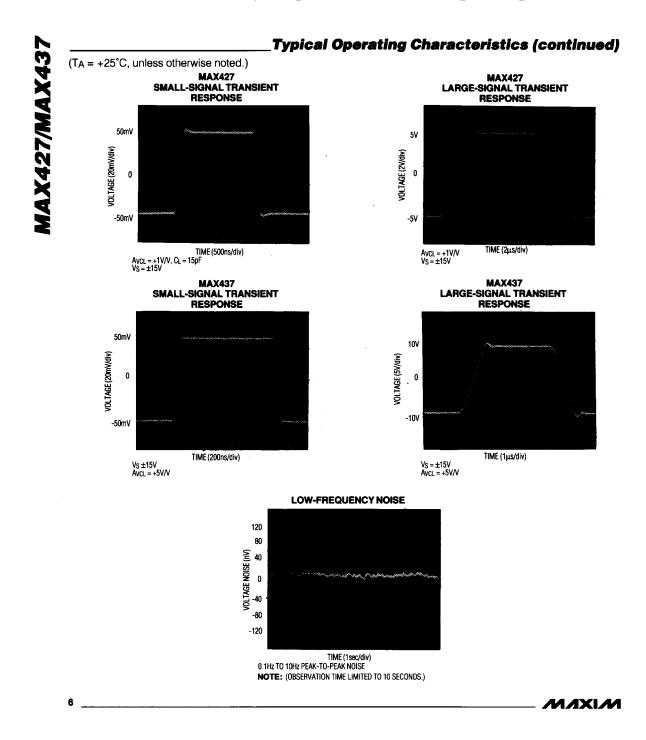
Note 6: See the test circuit and frequency response curve for 0.1Hz to 10Hz tester in the Applications Information section.

Note 7: See the test circuit for current noise measurement in the *Applications Information* section.
 Note 8: The average input offset drift performance is within the specifications unnulled or when nulled with a pot having a range of 8kΩ to 20kΩ. Contact factory for the availability of a higher-performance, 100% tested drift parameter of 0.4μV/°C max.

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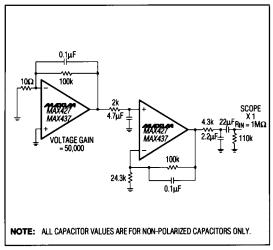


Figure 1. Voltage-Noise Test Circuit (0.1Hz to 10Hz)

#### **Applications Information**

The MAX427/MAX437 provide stable operation with load capacitances of up to 2nF and  $\pm$ 10V output swings; larger capacitances should be decoupled with a 50 $\Omega$  series resistor inside the feedback loop. The MAX427 is unitygain stable and the MAX437 is stable at gains of five or greater.

Thermoelectric voltages generated by dissimilar metals at the input terminals degrade the drift performance. Connections to both inputs should be maintained at the same temperature for best operation.

#### **Offset-Voltage Adjustment**

Input offset voltage (Vos) is trimmed at the wafer level. If Vos adjustment is necessary, a 10k $\Omega$  trim potentiometer (pot) may be used and will not degrade TCVos (Figure 3). Other trim pot values from 1k $\Omega$  to 1M $\Omega$  can be used with a slight degradation (0.1 $\mu$ V/°C to 0.2 $\mu$ V/°C) of TCVos. Adjusting, but not zeroing, Vos creates a drift of approximately (Vos/300) $\mu$ V/°C. The adjustment range with a 10k $\Omega$  trim pot is ±4mV. For a smaller range, reduce nulling sensitivity by connecting a smaller pot in series with fixed resistors; for example, Figure 4 has a ±70 $\mu$ V adjustment range.

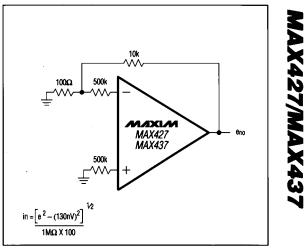


Figure 2. Current-Noise Test Circuit

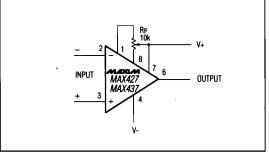
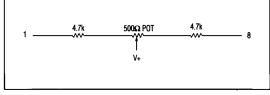


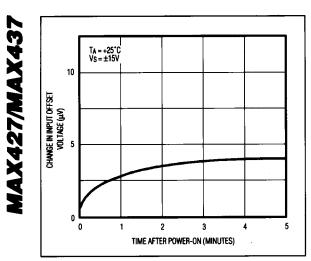
Figure 3. Offset Nulling Circuit



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**Ultra-Low Noise, High-Precision Op Amps** 

Figure 5. Warm-Up Offset Voltage Drift

#### Noise Measurements

To measure the  $60nV_{p-p}$  noise specification of the MAX427/MAX437 in the 0.1Hz to 10Hz range, observe the following precautions:

1. The device must warm up for at least five minutes. Figure 5 shows how Vos typically increases  $4\mu$ V with increases in chip temperature after power-up. In the 10sec measurement interval, temperature-induced effects can exceed 10nV.

2. For similar reasons, the device must be well-shielded from air currents, including those caused by motion. This minimizes thermocouple effects.

3. As shown in Figure 6, the 0.1Hz corner is defined by only one zero. A maximum test time of 10sec acts as an additional zero to eliminate noise contributions from the frequency band below 0.1Hz.

4. A noise-voltage-density test is recommended when measuring noise on a large number of units. A 10Hz noise-voltage-density measurement correlates well with a 0.1Hz to 10Hz peak-to-peak noise reading, since both results are determined by the white noise and the location of the 1/f corner frequency.

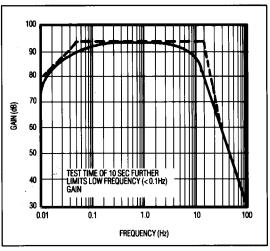


Figure 6. 0.1Hz to 10Hz Vp-p Noise Tester Frequency Response

#### Unity-Gain Buffer Applications (MAX427 Only)

Figure 7 shows the circuit and output waveform with  $R_f \le 100\Omega$ , and the input driven with a fast, large signal pulse (>1V).

During the fast rise portion of the output, the input protection diodes short the output to the input, and a current, limited only by the output short-circuit protection, is drawn by the signal generator. With Rf  $\geq$  500 $\Omega$ , the output is capable of handling the current requirement (IL  $\leq$  20mA at 10V) and a smooth transition occurs.

When  $R_f \ge 2k\Omega$ , a pole created with  $R_f$  and the amplifier's input capacitance (8pF) causes additional phase shift and reduces phase margin. A small capacitor (20pF to 50pF) in parallel with  $R_f$  eliminates this problem.

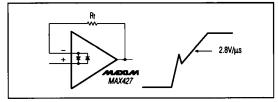


Figure 7. Pulsed Operation of Unity-Gain Buffer

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#### **Comments on Noise**

The MAX427/MAX437 are very low-noise amplifiers. They achieve outstanding input voltage noise characteristics by operating the input stage at a high quiescent current. Input bias and offset currents, which would normally increase with the quiescent current, are minimized by bias-current cancellation circuitry. The MAX427/MAX437 have IB and IOs of only ±35nA and 30nA respectively at +25°C. This is particularly important with high source-resistances.

Voltage noise is inversely proportional to the square-root of bias current, but current noise is proportional to the square-root of bias current. The MAX427/MAX437 lownoise advantages are reduced when high source resistors are used.

Total noise =  $[(voltage noise)^2 + (current noise x Rs)^2 + (resistor noise)^2]^{1/2}$ 

Figure 8 shows noise vs. source resistance at 1kHz. To use this plot for wideband noise, multiply the vertical scale by the square-root of the bandwidth. The MAX427/MAX437 maintain low input noise voltage with Rs < 1kΩ. With Rs > 1kΩ, total noise increases and is dominated by the resistor noise, not the current or the voltage noise. It is only with Rs ≥ 20kΩ that current noise dominates. Current noise is not important for applications with Rs < 20kΩ. The MAX427/MAX437 have lower total noise than the MAX400/OP07 for Rs < 10kΩ. As Rs increases, the crossover between the MAX427/MAX437 and the MAX400/OP07 noise occurs in the Rs = 15kΩ to 40kΩ region.

Figure 9 shows 0.1Hz to 10Hz peak-to-peak noise. Here, resistor noise is negligible and current noise (in) becomes important, because in  $\propto 1/\sqrt{f}$ . The crossover with the MAX400/OP07 occurs in the Rs =  $3k\Omega$  to  $5k\Omega$  range, depending on whether balanced or unbalanced source resistors are used (at  $3k\Omega$  the Ig and Ios error can be three times the Vos specification). For low-frequency applications, the MAX400/OP07 are better than the MAX427/MAX437 when Rs >  $3k\Omega$ , except when gain error is important. Figure 10 illustrates the 10Hz noise. As expected, the results fall between those of the previous two figures.

For reference, typical source resistances of some signal sources are listed in Table 1.

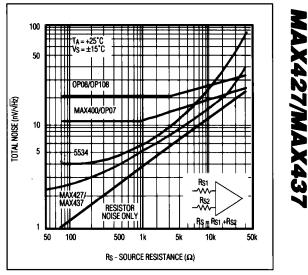


Figure 8. Noise vs. Source Resistance (Including Resistor Noise) at 1kHz

Table 1. Signal Source vs. Source Impedance

DEVICE	SOURCE IMPEDANCE	COMMENTS
Strain Gauge	<500Ω	Typically used in low- frequency applications.
Magnetic Tapehead	< 1500Ω	Low IB is very important to reduce self-magnetization problems when direct coupling is used. MAX427 IB can be neglected.
Linear Variable Differential Transformer	< 1500Ω	Used in rugged servo-feed- back applications. Bandwidth of interest is 400Hz to 5kHz.

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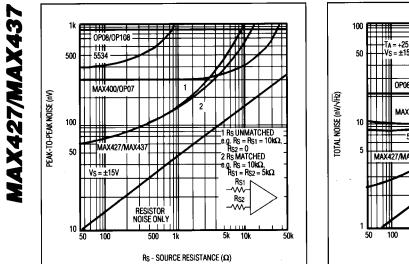


Figure 9. Peak-to-Peak Noise (0.1 to 10Hz) vs. Source Resistance (Includes Resistor Noise)

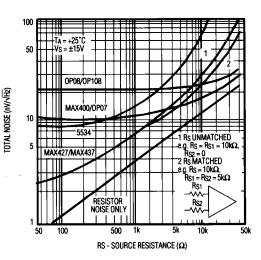
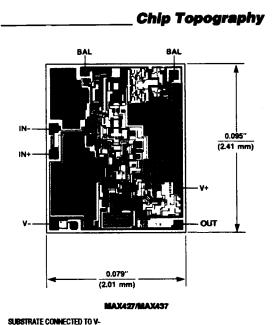


Figure 10. 10Hz Noise vs. Source Resistance (Includes Resistor Noise)

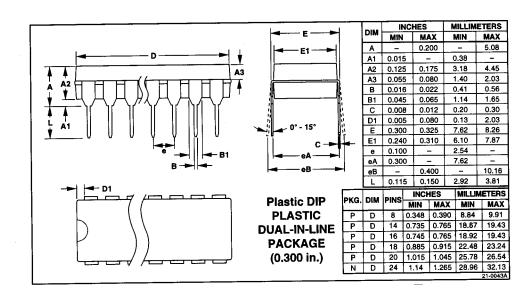
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MAX427/MAX437

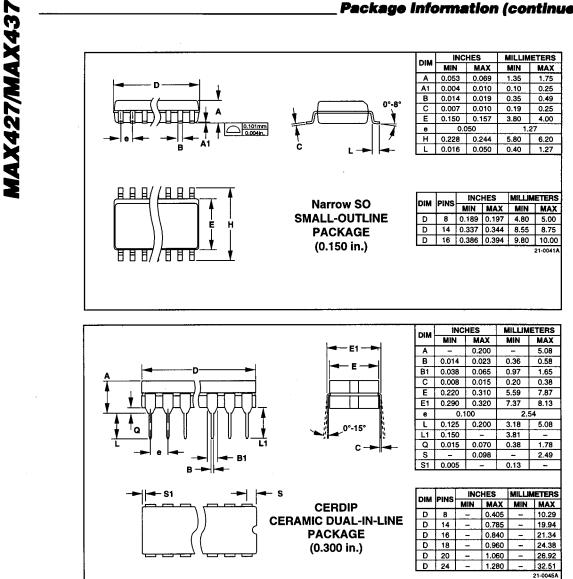
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**Package Information** 

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